



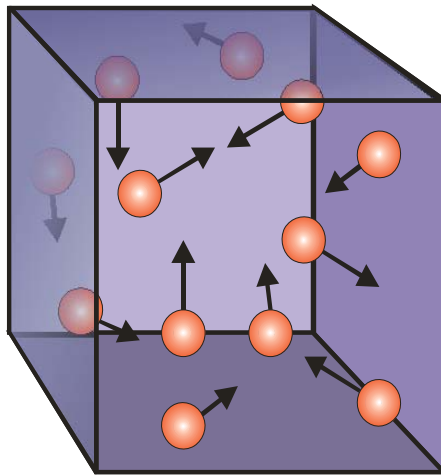
Quanteneffekte in Halbleiternanostrukturen

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Institut für Festkörperphysik
Gottfried Wilhelm Leibniz Universität Hannover
Germany**

Quantum Mechanics: Low-Dimensional Systems

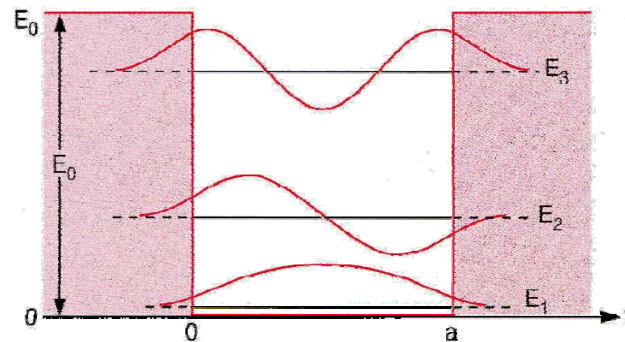
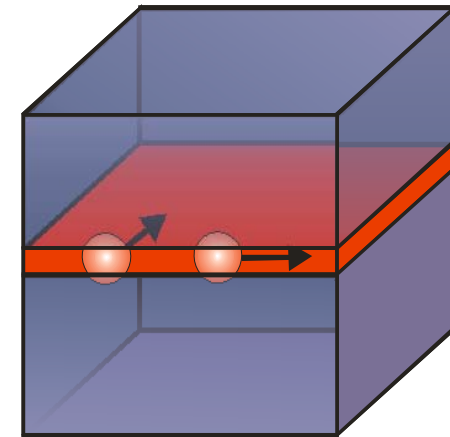
3d



quantum size effect

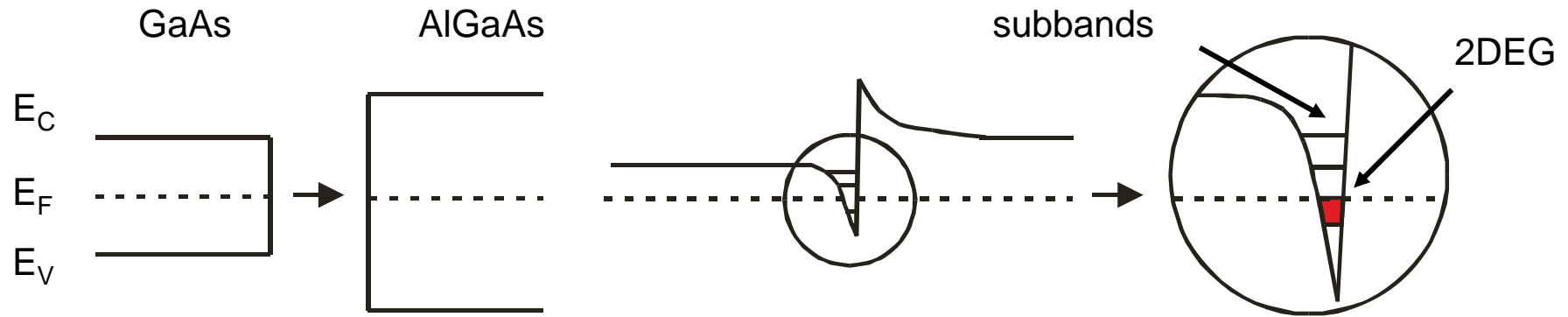


2d



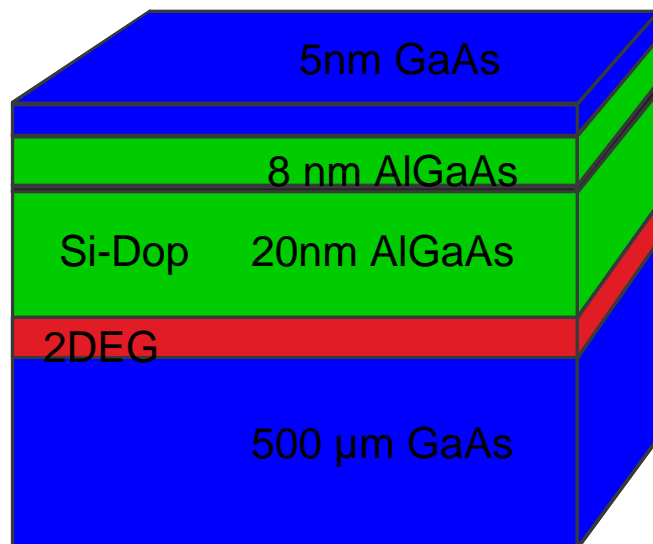
particles have signatures of waves

2D in Semiconducting Heterostructures



2d

- **band-edge discontinuity** produces **triangular well** → **2DEG**



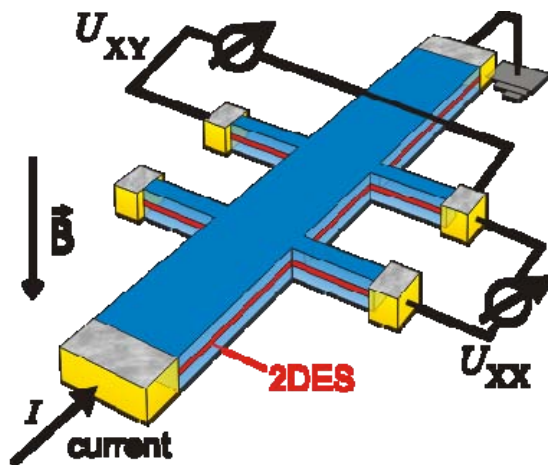
made by
molecular beam epitaxy

used in

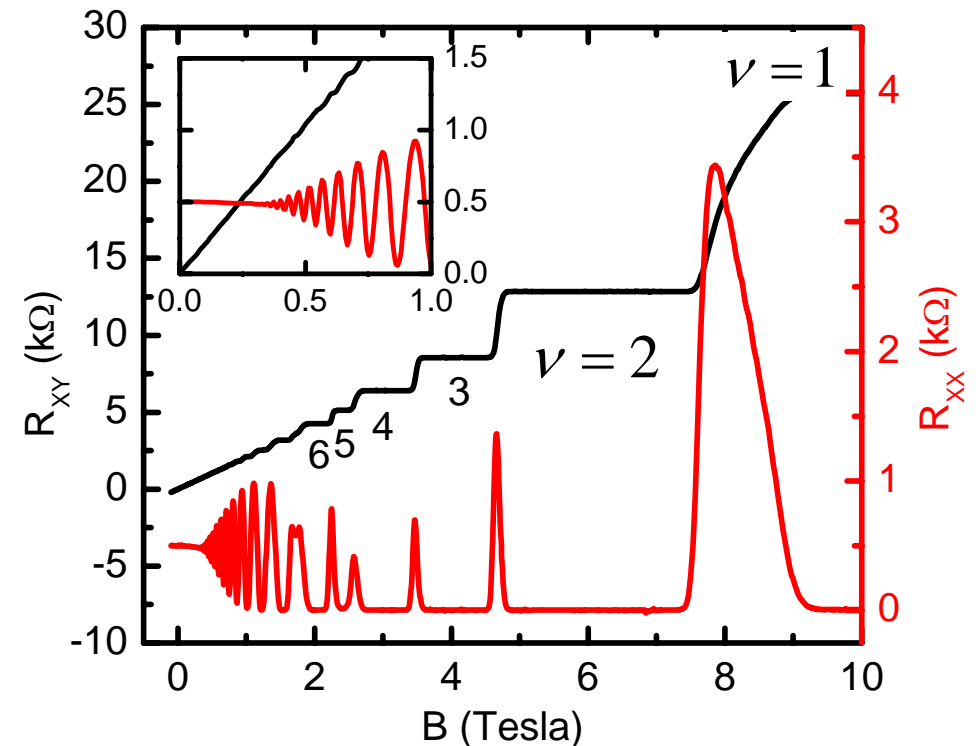


2d Physics: Quantum Hall Effect

DFG Priority Program: 2000 - 2006

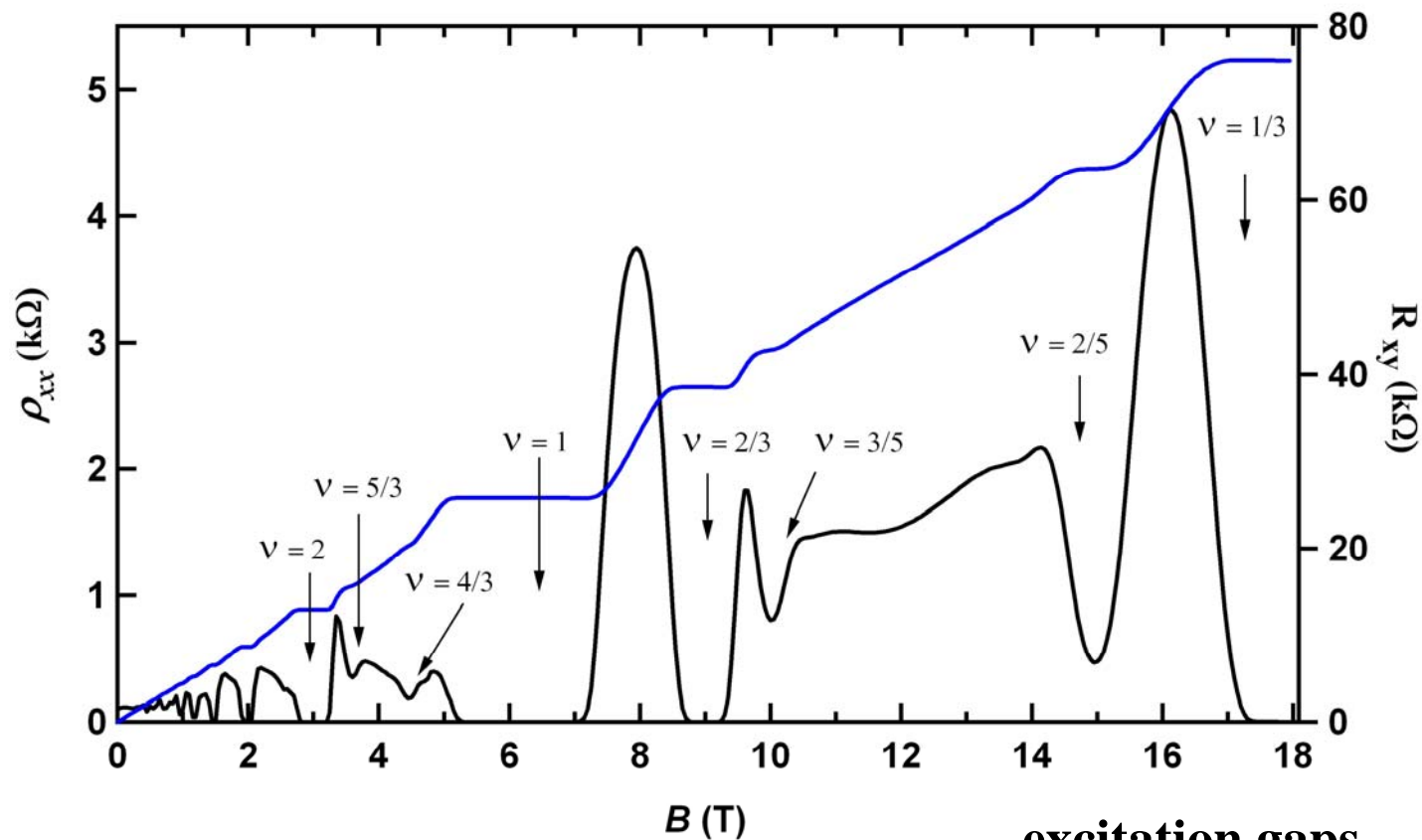


$$R_{XY} = \frac{U_{XY}}{I} = \frac{h}{ve^2} = \frac{1}{\nu} 25812,807 \Omega$$



- Phys. Rev. Lett. 93, 196801 (2004)
- Phys. Rev. Lett. 89, 276801 (2002)
- Phys. Rev. Lett. 88, 036802 (2002)
- Phys. Rev. Lett. 86, 5124 (2001)

Fractional Quantum Hall Effect



cond-mat/0607167

Phys. Rev. B 74, 165325 (2006)

Phys. Rev. B 74, 195324 (2006)

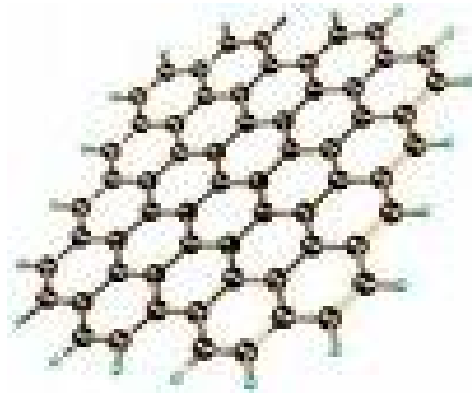
Phys. Rev. Lett. 92, 156401 (2004)

Phys. Rev. Lett. 93, 026801 (2004)

excitation gaps
effects of spin,
specific heat,
electrons versus holes

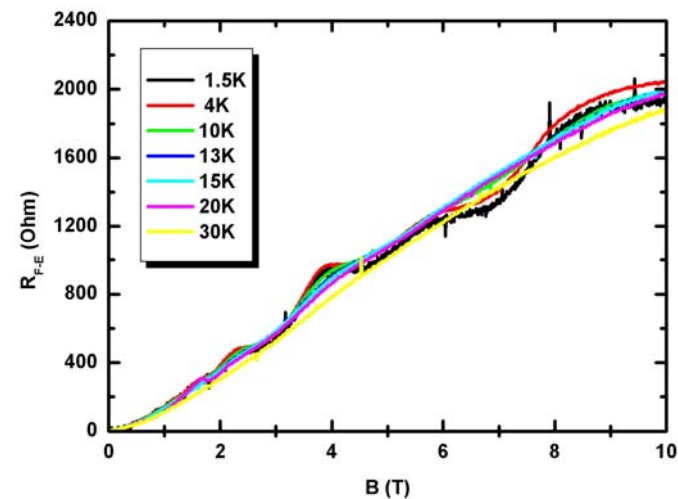
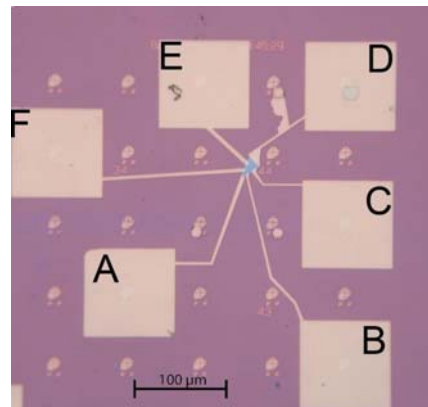
Quantum Hall Effect at Room Temperature

Novel Material: Graphene



Novoselov et al., Science 315 (2007)

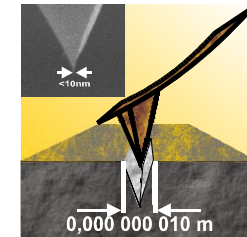
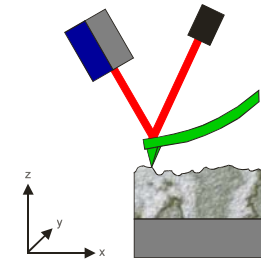
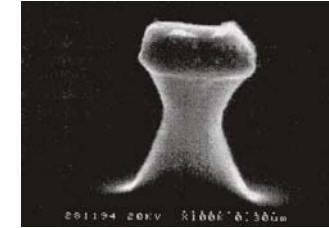
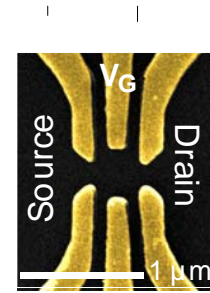
our measurements:
not yet as good



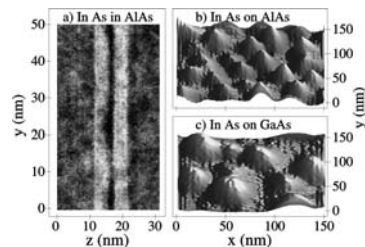


Low-Dimensional Structures: 1d, 0d

- lithography
 1. optical lithography
 2. electron beam lithography
 3. direct writing with atomic force microscope (AFM)



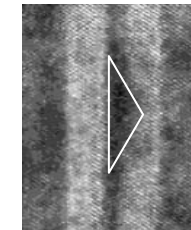
- self-organized growth
quantum dots (InAs, Si, Ge)



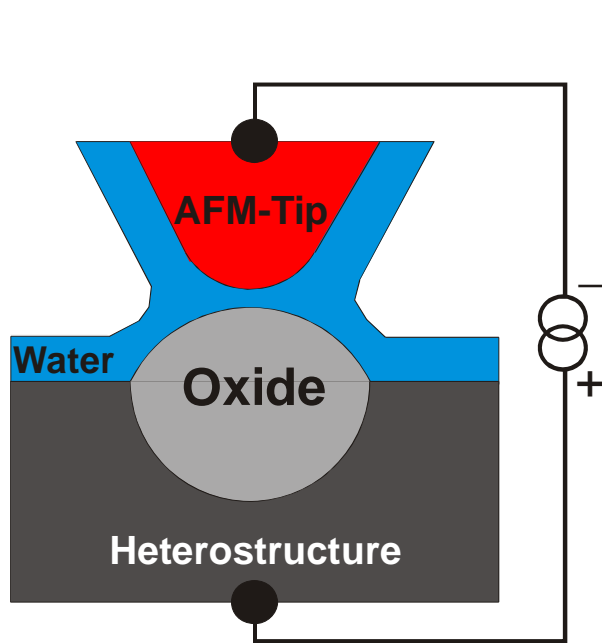
lattice mismatch between InAs and AlAs (GaAs): 7%

Stranski Krastanov growth

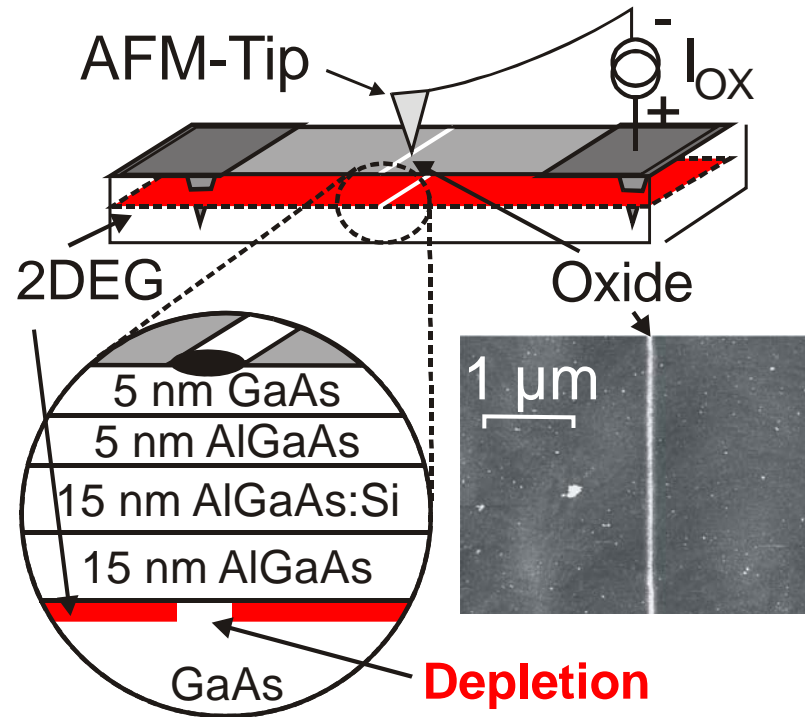
Appl. Phys. Lett. 82, 1209 (2003)



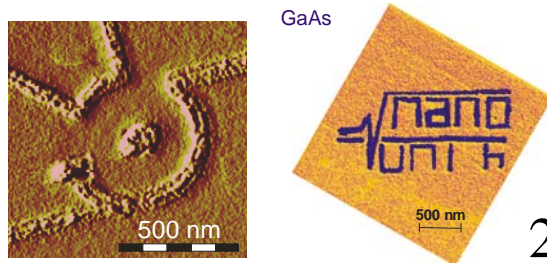
Local Oxidation with AFM



Appl. Phys. Lett. 76, 457 (2000)



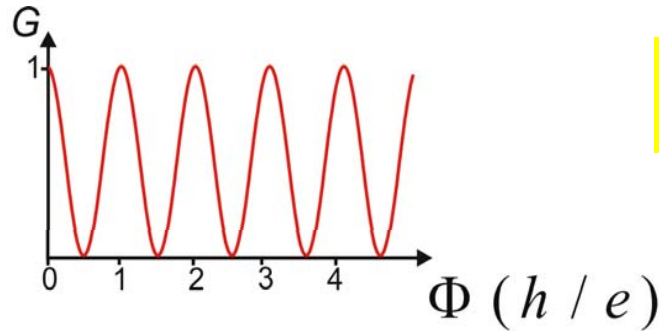
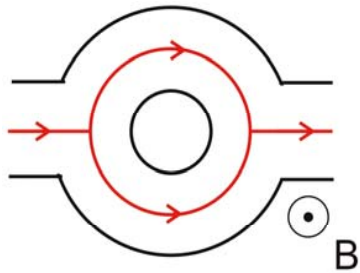
Ishii, Matsumoto (1995)



chemistry:

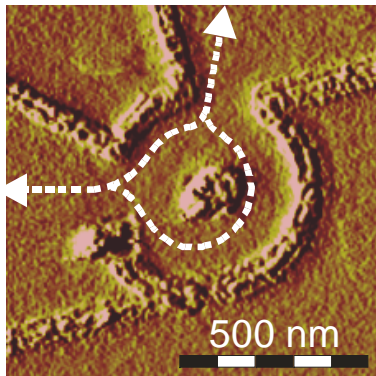
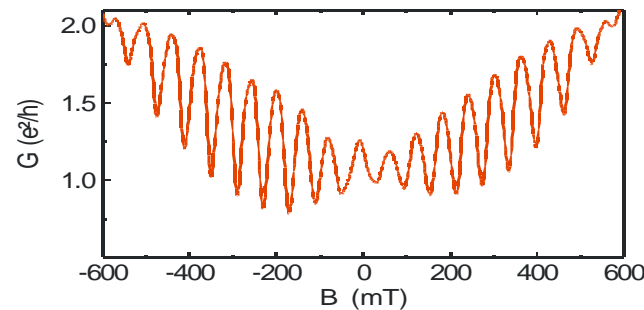


Interference Effects in Quantum Rings



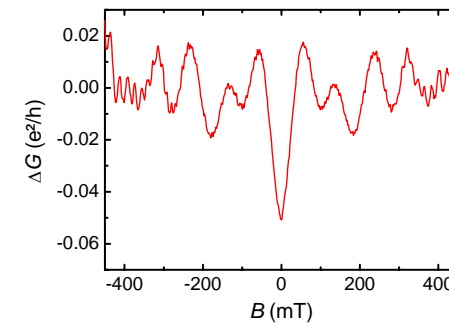
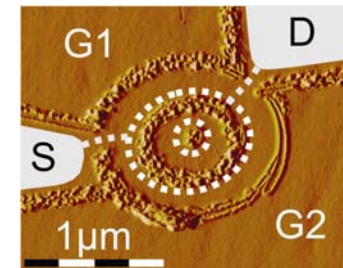
$$G \propto \cos(2\pi \Phi / \Phi_0)$$

flux quant.: $\Phi_0 = h / e$
 Aharonov-Bohm effect



up to 50% modulation of
 the conduct. periodicity
 58mT: R=150nm

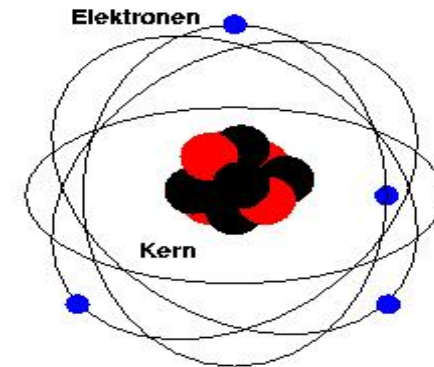
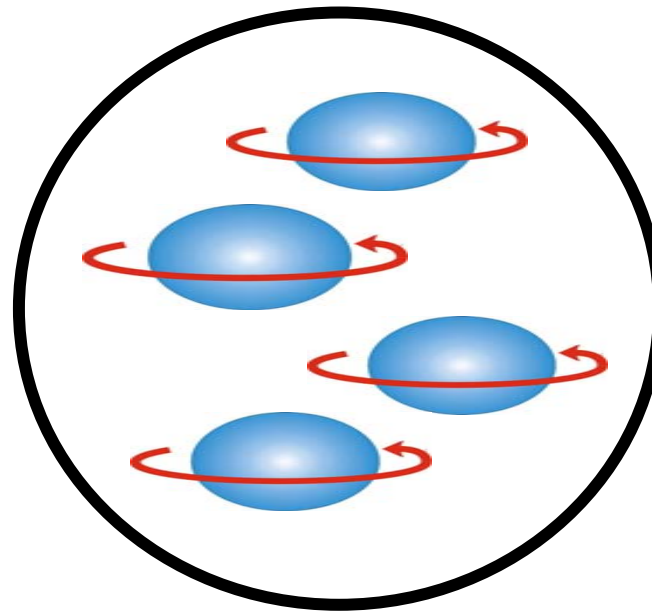
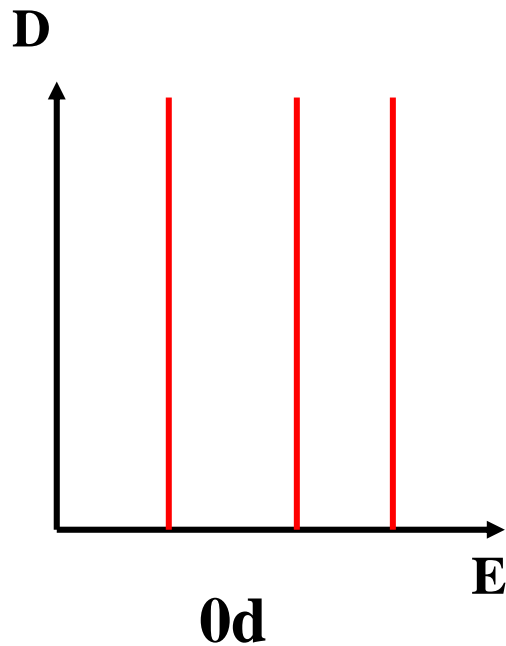
2 rings:



Phys. Rev. Lett. 90, 196601 (2003)

Quantum Dot: quasi-zero-dimensional system in a semiconductor

artificial atom?!

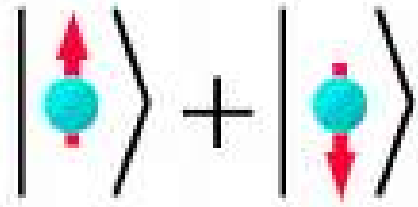


Bohr radius

$$a_B = \frac{4\pi\hbar^2 \epsilon\epsilon_0}{me^2}$$

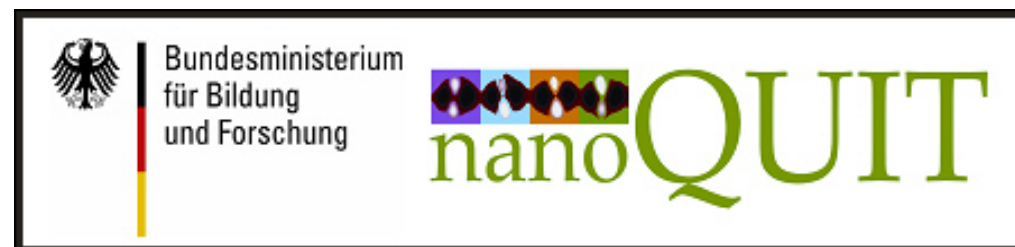
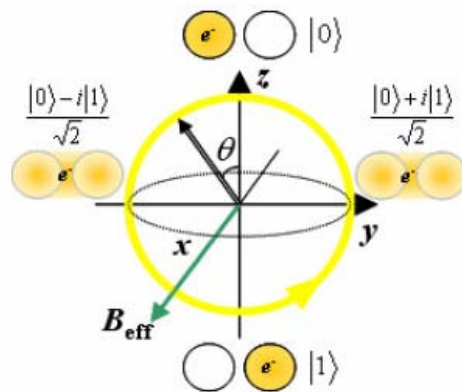
charge, spin,
interaction effects,
quantum information processing

Quantum Information Processing: Calculating with Quantum Mechanics

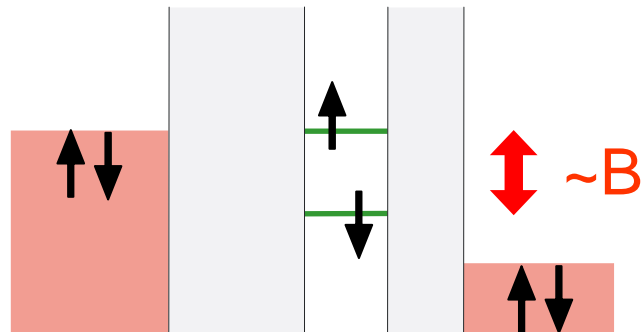
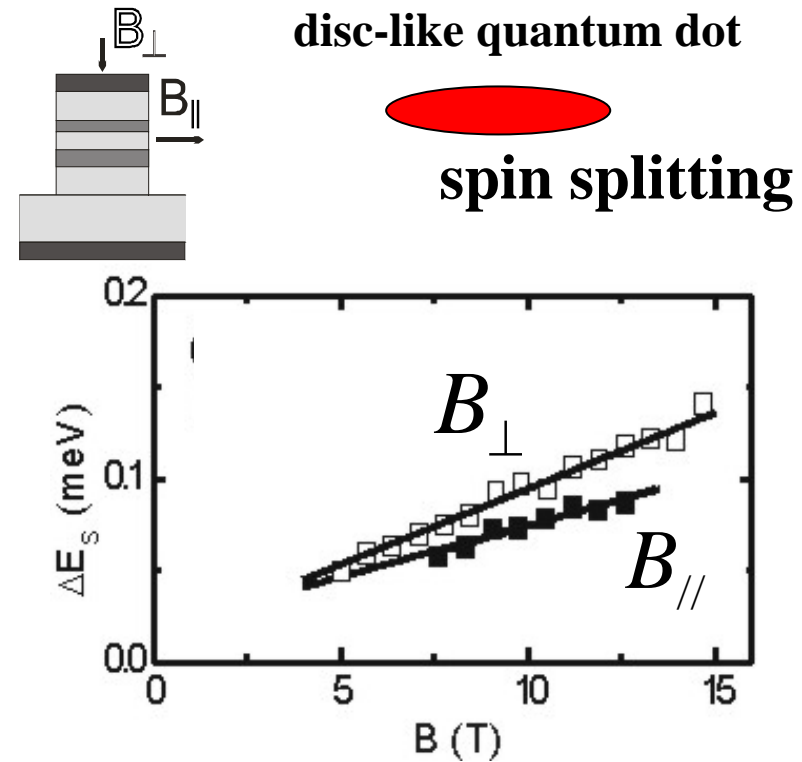
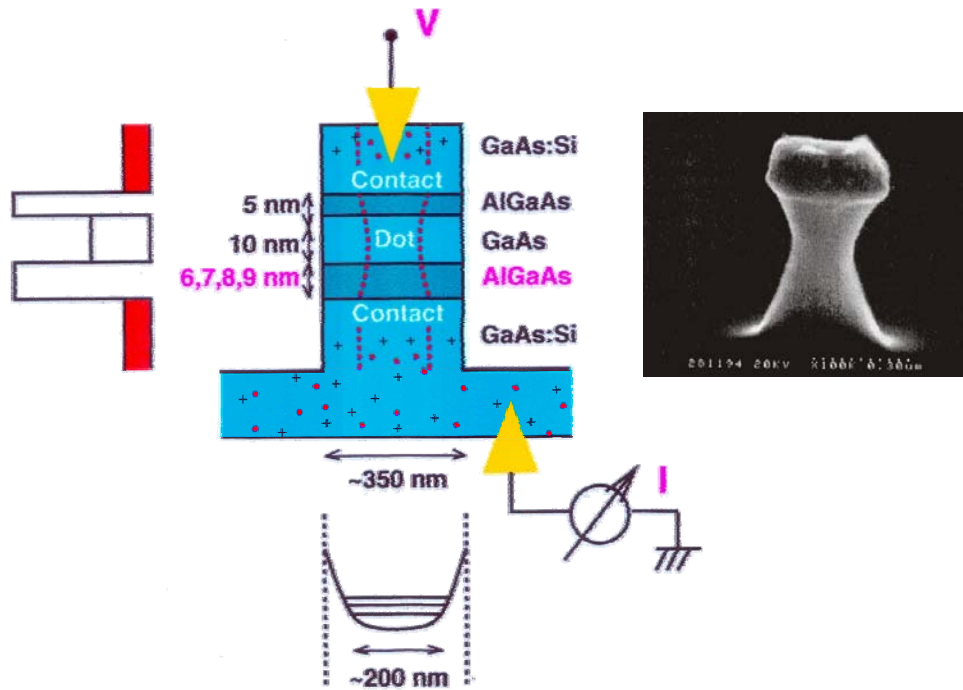


two-level systems in
quantum dots:

- charge
- spin



Spin Effects in Single Dots



differences due to spin-orbit effects

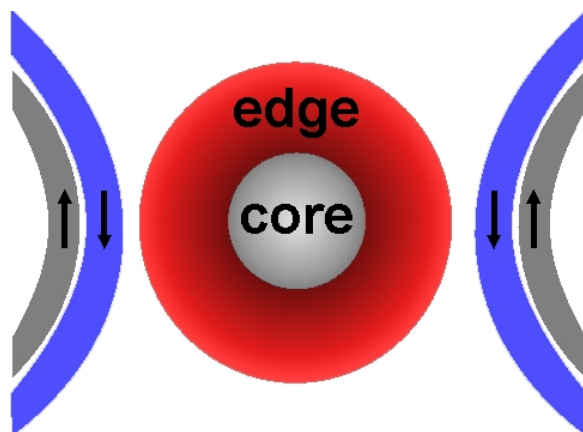
Phys. Rev. Lett. 94, 226404 (2005)

extreme anisotropy: holes in SiGe/Ge structure
 $g=6.2 \rightarrow 0$

Phys. Rev. Lett. 96, 086403 (2006)

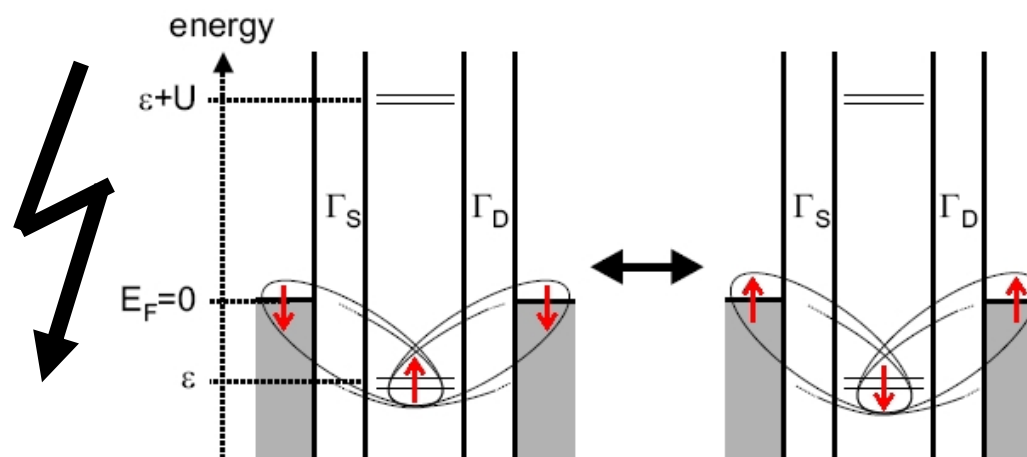
Interaction Effects in Single Dots: Kondo Effect versus Spin Blockade

spin blockade



spin-polarized leads necessary

Kondo effect



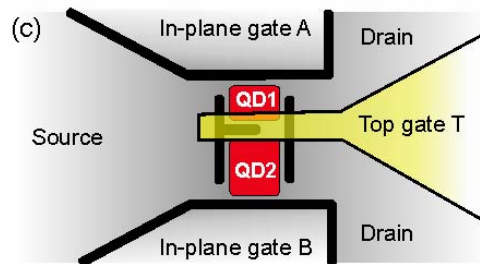
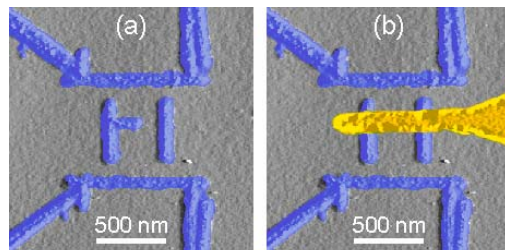
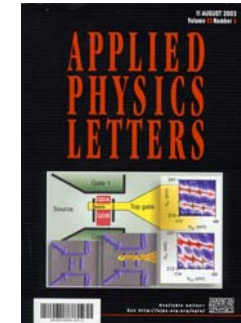
both spins in the leads necessary

→ spin structure of many-electrons quantum dots

Phys. Rev. Lett. 96, 046802 (2006)

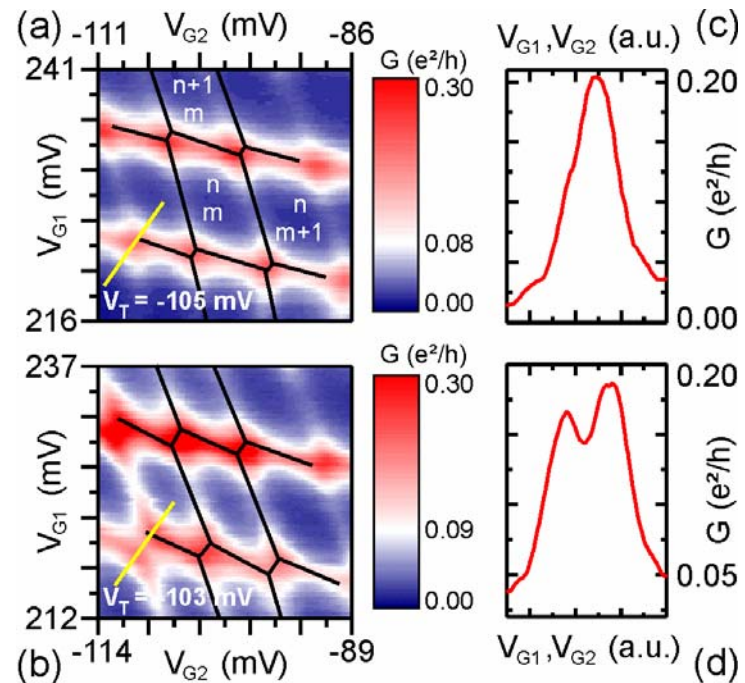
Phys. Rev. Lett. 96, 176801 (2006)

Coupling between Quantum Dots: Artificial Molecule



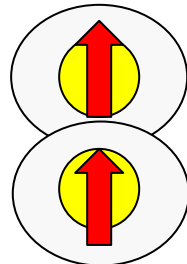
Appl. Phys. Lett. 83, 1163 (2003)

Appl. Phys. Lett. 85, 806 (2004)



weak
coupling

strong
coupling



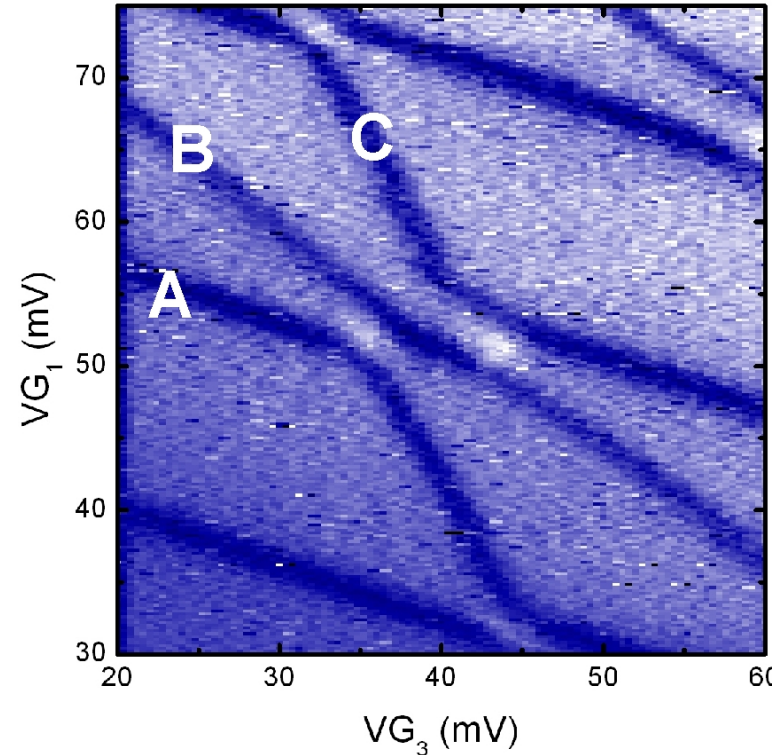
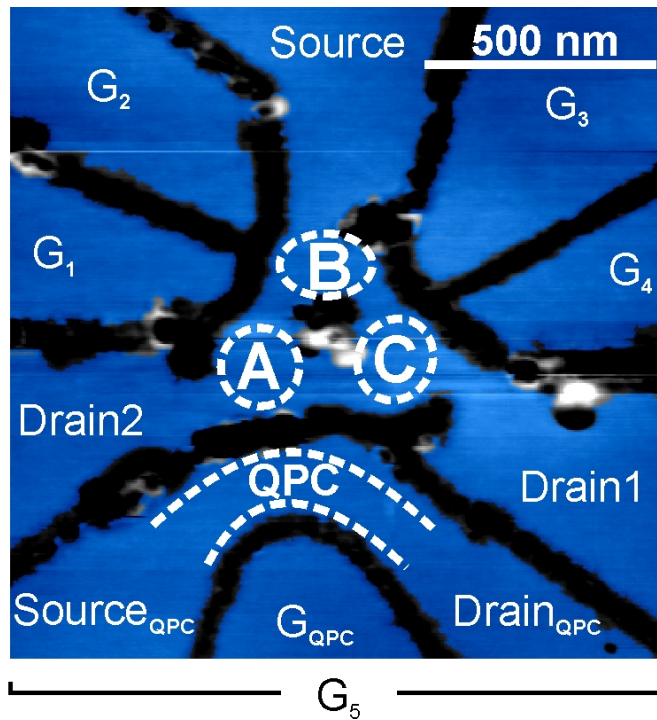
**coupled quantum dots:
building blocks of quantum comp.**

Phys. Rev. Lett. 96, 246803 (2006)

Phys. Rev. Lett. 80, 4032 (1998)

Phys. Rev. Lett. 81, 689 (1998)

Triple Quantum Dot

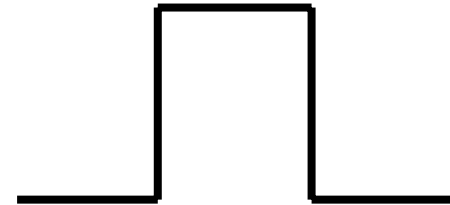
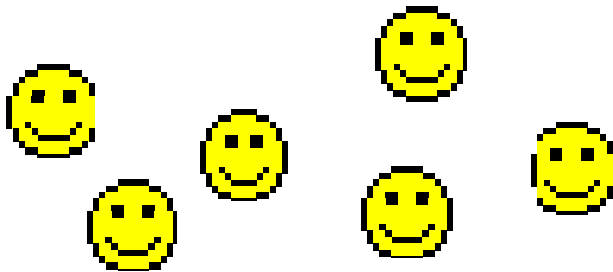


- triple quantum dot made with local anodic oxidation
- charge detection with quantum point contact

Shot Noise

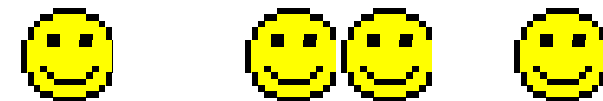
- electrical current

barrier

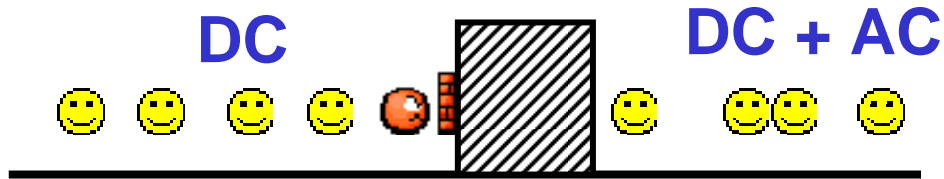


DC

DC + AC



Shot Noise Suppression

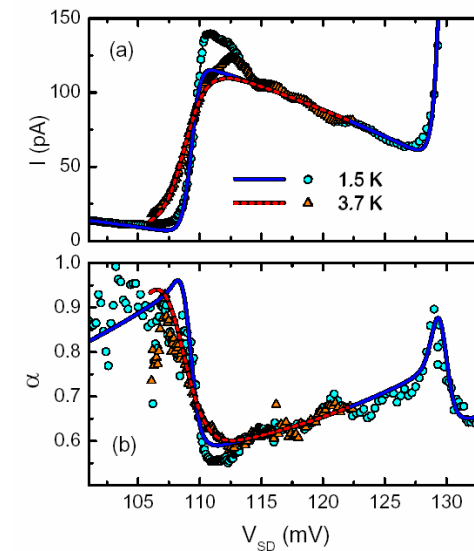
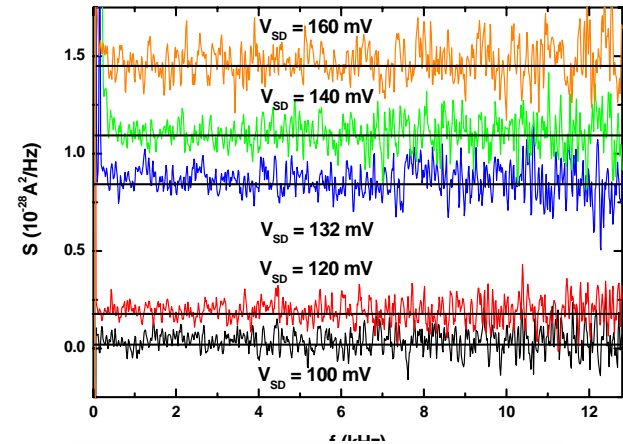
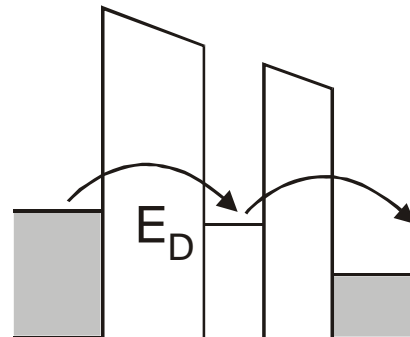


$$S_{\text{Poisson}} = 2eI \quad (\text{single barrier})$$

correlations can suppress noise

$$S = \alpha 2eI$$

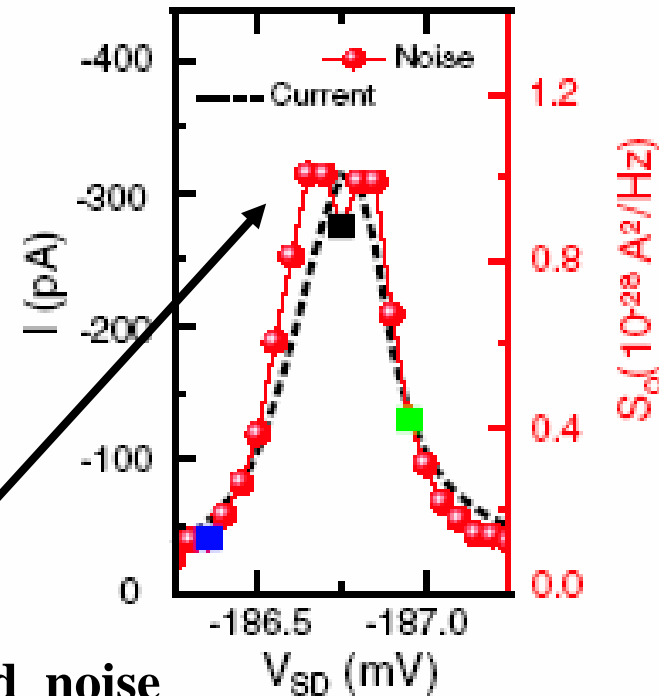
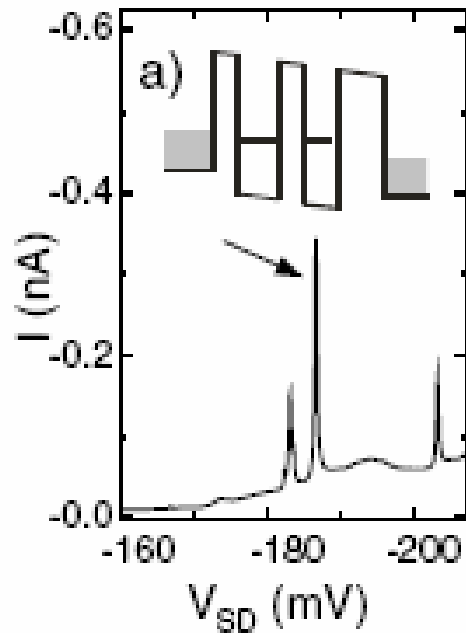
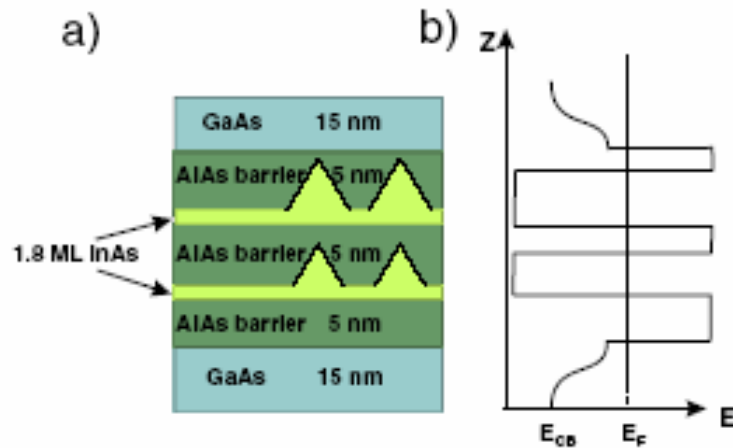
Fano factor



Phys. Rev. B 66,161303 (2002)

Phys. Rev. B 69, 113316 (2004)

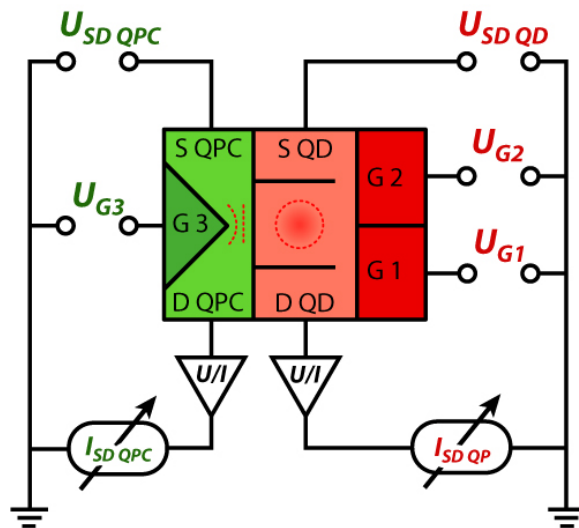
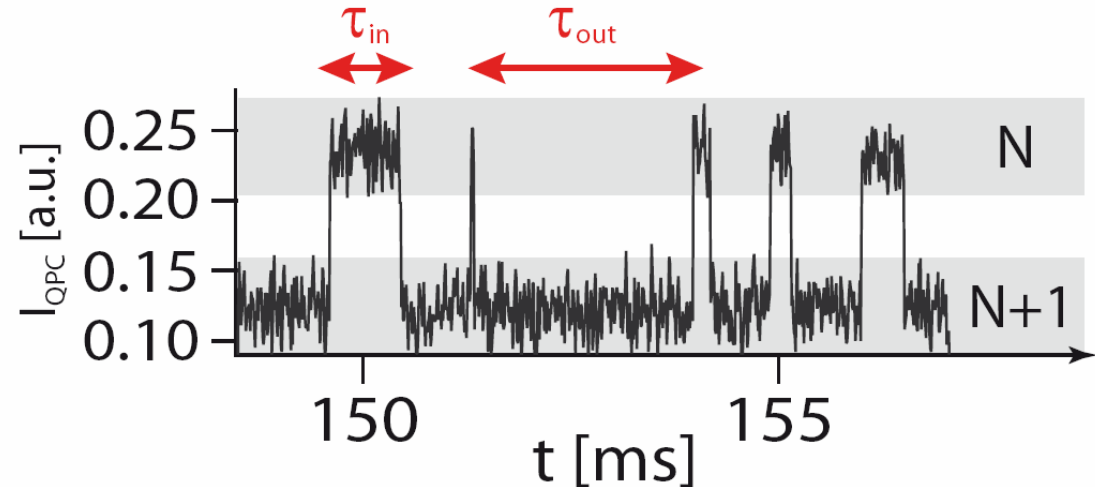
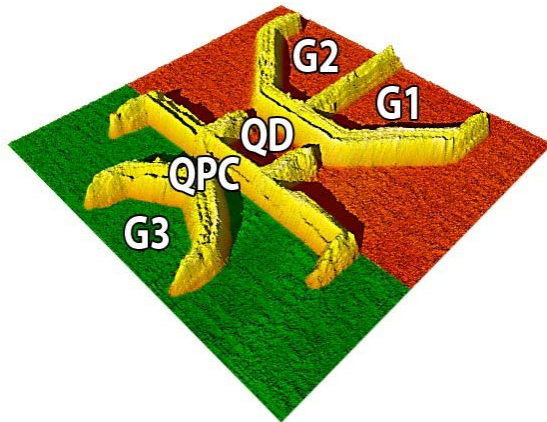
Shot Noise in Coupled Quantum Dots



enhanced noise
due to ??
coupling effects, interactions, ...

Phys. Rev. Lett. 96, 246803 (2006)

Real Time Detection of Single Electrons



direct analysis of tunneling properties

tunneling times, distribution,
counting statistics

Fano factor, ...

Phys. Rev. B 72, 193302 (2005)

Phys. Rev. B 72, 233402 (2005)



N. Maire



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A. Hadzibrahimovic



O. Agafonov



P. Barthold



M. Rogge



N. Ubbelohde



T. Ridder



Q. Ahmad



F. Luque



C. Fricke



A. Mühle



H. Schmidt